## **Technical Information**

Index of Key Symbols			
В	Base connection	Kv	Thermal resistance correction factor
С	Capacitance; junction capacitance;	P <sub>tot</sub>	Power dissipation
	Collector connection	Po	Continuous power dissipation
$C_{cso}$	Collector base capacitance (open emitter)	$P_{l}$	Pulse power dissipation
CEBO	Emitter base capacitance (open collector)	r <sub>b</sub> . c <sub>c</sub>	Collector base time constant
$C_{iss}$	Input capacitance	r <sub>thA</sub>	Pulse thermal resistance junction to ambient air
E	Emitter connection	r <sub>thC</sub>	Pulse thermal resistance junction to case
f	Frequency	R	Resistance; resistor
f <sub>r</sub>	Gain bandwith product	$R_{_{BE}}$	Resistance between base and emitter
F	Noise figure	R,	Load resistance
F <sub>c</sub>	Noise figure in mixer stages	$R_s$	Series resistance
ħ	Parameters of h-(hybrid) matrix	$R_{th}$	Thermal resistance
h <sub>f</sub>	Small signal current gain	$R_{thA}$	Thermal resistance junction to ambient air
h <sub>i</sub>	Input impedance	$R_{thC}$	Thermal resistance junction to case resp. mounting
h <sub>o</sub>	Output admittance		base
h <sub>r</sub>	Reverse voltage transfer ratio	R <sub>thC/S</sub>	Thermal resistance case or mounting base to heat
h <sub>FE</sub>	DC current gain, common emitter		sink
l <sub>B</sub>	Base current	R <sub>ths</sub>	Thermal resistance heat sink to ambient air
I <sub>BM</sub>	Peak base current	t	Time
l <sub>B1</sub>	Turn-on current	t <sub>d</sub>	Delay time
l <sub>B2</sub>	Turn-off current	t,	Fall time
I <sub>c</sub>	Collector current	t <sub>off</sub>	Turn-off time (ts+tf)
I <sub>CAV</sub>	Average collector current	t <sub>on</sub>	Turn-on time (td+tr)
I <sub>CBO</sub>	Collector base cutoff current (open emitter)	t <sub>p</sub>	Pulse duration
I <sub>CEO</sub>	Collector emitter cutoff current (open base)	t <sub>pd</sub>	Propagation delay time
I <sub>CER</sub>	Collector emitter cutoff current (specified	t,	Rise time
	resistance between base and emitter)	t <sub>s</sub>	Storage time
CES	Collector emitter cutoff current (base short-	t <sub>total</sub>	Total switching time (ton+toff)
	circuted to emitter)	T	Temperature; duration of one period
I <sub>CEV</sub>	Collector emitter cutoff current (sepcified	T <sub>amb</sub>	Ambient temperature
	voltage between base and emitter)	$T_{j}$	Junction temperature
I <sub>CM</sub>	Peak collector current	T <sub>c</sub>	Case temperature
IE	Emitter current	$T_{s}$	Storage temperature
I <sub>EBO</sub>	Emitter base cutoff current (open collector)	T <sub>SB</sub>	Temperature of substrate backside







## **Technical Information**

## Index of Key Symbols

V Voltage

V<sub>BB</sub> Base supply voltage

 $V_{_{\rm BE}}$  Base emitter voltage

V<sub>BEsat</sub> Base emitter saturation voltage

V<sub>(BR)CEO</sub> Collect base breakdown voltage (open emitter)
V<sub>(BR)CEO</sub> Collector emitter breakdown voltage (open base)

V<sub>(BR)CER</sub> Collector emitter breakdown voltage

(specified resistance between base and emitter)

V<sub>(BR)CES</sub> Collector emitter breakdown voltage

(emitter short-circuited to base)

V<sub>(BR)EBO</sub> Emitter base breakdwon voltage (open collector)

V<sub>CB</sub> Collector base voltage

V<sub>CBO</sub> Collector base voltage (open emitter)

V<sub>cc</sub> Collector supply voltageV<sub>ce</sub> Collector emitter voltage

V<sub>CEO</sub> Collector emitter voltage (open base)

V<sub>CER</sub> Collector emitter voltage

(specified resistance between base and emitter)

V<sub>CES</sub> Collector emitter voltage (emitter short-circuit to base)

V<sub>CEsat</sub> Collector emitter saturation voltage

V<sub>CEV</sub> Collector emitter voltage

(specified voltage between base and emitter)

V<sub>EBO</sub> Emitter base voltage (open collector)

V<sub>EE</sub> Emitter supply voltage

V<sub>i</sub> Input voltageV<sub>o</sub> Output voltage

T<sub>s</sub> Storage time constant

ν Duty cycle (tp/T)



